

CMOS CURRENT MODE PWM CONTROLLER

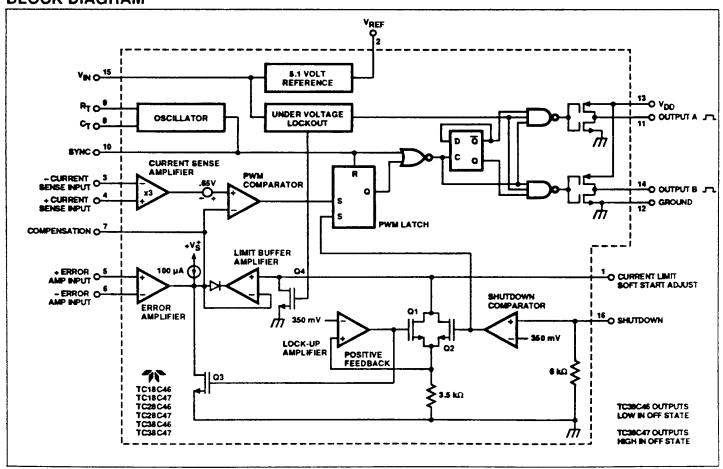
FEATURES

isolated Output Drive
Low Power CMOS Construction
Low Supply Current2 mA Typ
Wide Supply Voltage Operation8V to 18V
Latch-Up Immunity500 mA on Outputs
Above and Below Rail Input Protection6V
High Output Drive500 mA Peak
Current Mode Control
Fast Rise/Fall Time50 ns @ 1000 pF
High Frequency Operation500 kHz
UV Hysteresis Guaranteed

Programmable Current Limit
Shutdown Pin Available
Double Ended
Soft Start
Low Prop Delay Current Amp
to Output < 350 ns Typ
Low Prop Delay Shutdown
to Output< 400 ns Typ
TC38C46/47 Pin Compatible with
Unitrode UC3846/3847

ESD Protected±2 kV

BLOCK DIAGRAM



1017 2

GENERAL DESCRIPTION

The TC38C46/47 are current mode CMOS PWM control ICs. These only draw 2 mA supply current, so they can be driven without a costly 50-60 Hz transformer. The output drive stage is capable of high drive currents, 300 mA typical.

The TC38C46/47 are pin compatible with earlier bipolar products so that designers can easily update older designs. A number of improvements have been added.

This second generation part has been designed with an isolated drive stage. Unlike its cousin, the TC170, the output stage of the TC38C46/47 can be run from a separate power supply such as a secondary winding on an output transformer. This allows for bootstrap start-up of the power supply.

ORDERING INFORMATION

Part No.	Configuration	Pkg./Temperature
TC18C46MJE	Non-Inverting	16-Pin CerDIP
		-55 to +125°C
TC18C47MJE	Inverting	16-Pin CerDIP
		-55 to +125°C
TC28C46EOE	Non-Inverting	16-Pin SOIC (wide)
		-40 to +85°C
TC28C46EPE	Non-Inverting	16-Pin Plastic DIP
		-40 to +85°C
TC28C47EOE	Non-Inverting	16-Pin SOIC (wide)
		-40 to +85°C
TC28C47EPE	Non-Inverting	16-Pin Plastic DIP
		-40 to +85°C
TC38C46COE	Non-Inverting	16-Pin SOIC (wide)
		0 to +70°C
TC38C46CPE	Non-Inverting	16-Pin Plastic DIP
		0 to +70°C
TC38C47COE	Inverting	16-Pin SOIC (wide)
		0 to +70°C
TC38C47CPE	Inverting	16-Pin Plastic DIP
		0 to +70°C

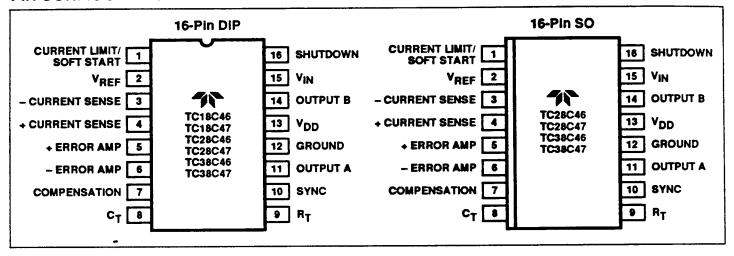
ABSOLUTE MAXIMUM RATINGS

Output Current, Source or Sink (Pins 1, 14)	500 mA
Analog Inputs (Pins 3, 4, 5, 6, 16)	0.3V to +VIN
Reference Output Current (Pin 2)	30 mA
Sync Output Current (Pin 10)	5 mA
Error Amplifier Output Current (Pin 7)	5 mA
Soft Start Sink Current (Pin 1)	50 mA
Oscillator Charging Current (Pin 9)	5 mA
Supply Voltage	18V
Maximum Chip Temperature	150 °C
Storage Temperature65°	C to +150°C
Lead Temperature (10 sec)	300 °C
Package Thermal Resistance	
CerDIP ReJ-A	150°C/W
CerDIP ReJ-C	55°C/W
PDIP ReJ.A	125°C/W
PDIP Rel-c	45°C/W
SOIC Reu-A	250°C/W
SOIC Reu-A	75°C/W

NOTES: 1. All voltages are with respect to Ground, Pin 12. Currents are positive into, negative out of the specified terminal.

2. Static-sensitive device. Unused devices must be stored in conductive material. Protect devices from static discharge and static fields. Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to Absolute Maximum Rating Conditions for extended periods may affect device reliability.

PIN CONFIGURATION



ELECTRICAL CHARACTERISTICS: unless otherwise stated, these specifications apply for $T_A = -55^{\circ}\text{C}$ to $+125^{\circ}\text{C}$ for TC18C46/TC18C47; -40°C to $+85^{\circ}\text{C}$ for the TC28C46/TC28C47; and 0°C to $+70^{\circ}\text{C}$ for the TC38C46/TC38C47; $V_{IN} = V_{DD} = 16V$; $V_{IN} = V$

		TC18C46/47 TC28C46/47			TC38C46/47			
Parameter	Test Conditions	Min	Тур	Max	Min	Тур	Max	Units
Reference Section								
Output Voltage	T _f = 25°C, I _O = 1 mA	5.0	5.1	5.2	5.0	5.1	5.2	V
Line Regulation	V _{IN} = 8V to 16V	—	±4	±20	—	±4	±20	mV
Load Regulation	l _O = 1mA to 10 mA	_	±4	±20		±4	±20	mV
Temp Coefficient	Over Operating Range, (note 1)		±0.2	±0.5	—	±0.2	±0.5	mV/°C
Total Output Range	Line, Load, and Temperature (note 1)	4.97	_	5.24	4.94	—	5.26	V
Long Term Drift	T _f = 125°C, 1000 Hrs (note 1)		±50	-		±50	1	mV
Short Circuit Output Current	V _{REF} = 0V	20	_	70	20	_	70	mA
Output Noise Voltage	10 Hz ≤ f ≤ 10 kHz,T _f = 25°C (note 1)	_	22	_		22		μV(rms)
Oscillator Section								
Initial Accuracy	T _f = 25°C	96.5	102	106.5	96.5	101	106.5	kHz
Voltage Coefficient	V _{IN} = 8V to 16V		±.1	±1.5	_	±.1	±1.5	%/V
Temp Coefficient	Over Operating Range (note 1)		±.04	±0.06	—	±.04	±0.06	%/°C
Clock Ramp Reset Current		1.2	2	3	1.2	2	3	mA
Osc Ramp Amplitude		3.6	3.8	4	3.6	3.8	4	V
Sync Output High Level	(note 1)	V _{DD} -0.5	-	_	V _{DD} -0.5	-	_	V
Sync Output Low Level	(note 1)	—	1 —	0.5	_	_	0.5	V
Sync Input High Level	Pin 8 = 0V, (note 1)	1 –	8.5		_	8.5	_	V
Sync Input Low Level	Pin 8 = 0V, (note 1)	_	8.5	5	_	8.5	5	V
Sync Input Current	Sync Voltage = 5.25V, Pin 8 = 0V	_	±5	±50		±5	±50	nA

ELECTRICAL CHARACTERISTICS (Cont): unless otherwise stated, these specifications apply for $T_A = -55$ °C to +125°C for TC18C46/TC18C47; -40°C to +85°C for the TC28C46/TC28C47; and 0°C to +70°C for the TC38C46/TC38C47; $V_{IN} = V_{DD} = 16V$; $R_T = 30.1k$; $C_T = 270$ pF.

		TC18C46/47 TC28C46/47			TC38C46/47			
Parameter	Test Conditions	Min	Тур	Max	Min	Тур	Max	Units
Error Amp Section								
Input Offset Voltage		_	±5	±25	_	±5	±25	mV
Input Bias Current		_	±10	±100	_	±0.1	±0.5	nA
Input Offset Current		—	±10	±100	 	±0.1	±0.5	nA
Open Loop Voltage Gain	$\Delta V_0 = 1 \text{ V to 6 V}, R_L = 100 \text{ k}$	70	90	_	70	90	_	dB
Gain Bandwidth Product	T ₁ = 25°C (note 1)	0.7	1	_	0.7	1	_	MHz
CMRR	V _{CM} = 0V to 11V	70	90	_	70	90		dB
PSRR	V _{IN} = 8V to 16V	70	90	_	70	90	_	₫B
Output Sink Current	V(EA -) = 5V, V(EA+) = 4.9V, V(COMP) = 1.2V	2	4	_	2	4		mA
Output Source Current	V(EA -) = 5V, V(EA+) = 5.1V, V(COMP) = 2.5V	5	10	_	5	10	_	mA
High Level Output Volt	$R_L = (COMP) 5 k\Omega$ to GND, $A_{CL} = 300$	4.9	5	5.1	4.9	5	5.1	V
Low Level Output Volt	$R_L = (COMP) 5 k\Omega$ to GND, $A_{CL} = 300$	_	0.4	0.9	_	0.4	0.9	V
Slew Rate		1.3	2	_	1.3	2		V/μs
Current Sense Sectio	n		-					
Amplifier Gain	(notes 2, 3)	2.7	3	3.4	2.7	3	3.4	V
Max Differential Input Signal (V _{Pin 4} -V _{Pin 3})	(note 2)	1.1	1.5	1.8	1.1	1.5	1.8	٧
Input Offset Voltage	(note 2)	0.4	0.65	0.85	0.4	0.65	0.85	V
CMRR	V _{CM} = 1V to 12V, (note 2)	40	60	—	40	60	—	dB
PSRR	V _{IN} = 8V to 16V, (note 2)	40	60		40	60	_	dB
Input Bias Current	(note 1)	_	±1	±100	—	±1	±100	nA
Input Offset Current	(note 1)	_	±0.1	±2	 	±0.1	±2	nA
Input Common Mode Rar	nge (note 1)	0	 -	11	0	I —	11	V
Delay to Outputs	T _f = 25°C, (note 1)	150	225	400	150	225	400	ns
Current Limit Adjust	Section							
Current Limit Voltage Off		-	±1	±25		±1	±25	mV
Input Impedance	(Shutdown Unlatched)	3	3.5	4	3	3.5	4	kΩ
Shutdown Terminal S		· · · · · · · · · · · · · · · · · · ·				<u></u>		
Threshold Voltage		320	360	400	320	360	400	m۷
Input Voltage Range	(note 1)	0	T —	VIN	0	 _	VIN	V
Min Latching Current (Ipin 1)	(note 4)	140	-	_	140	-	_	μА
Max Non-Latching Current (I _{Pin1})	(note 5)	-	_	65	_	-	65	μА
Min Pulse Width	(note 1)	100	50	1 -	100	50	T -	ns
Delay to Outputs	(note 1)	125	250	400	125	250	400	ns

ELECTRICAL CHARACTERISTICS (Cont): unless otherwise stated, these specifications apply for $T_A = -55^{\circ}\text{C}$ to +125°C for TC18C46/TC18C47; -40°C to +85°C for the TC28C46/TC28C47; and 0°C to +70°C for the TC38C46/TC38C47; $V_{IN} = V_{DD} = 16V$; $R_T = 30.1k$; $C_T = 270 \text{ pF}$.

		TC18C46/47 TC28C46/47			TC38C46/47			
Parameter Test Conditions		Min	Тур	Max	Min	Тур	Max	Units
Output Section								
Output Low Level rps (ON)	Isink = 20 mA	-	10	20		10	20	Ω
Output High Level rps (ON)		_	20	35		20	3 5	Ω
Output Rise Time	C _L = 1 mF	-	55	90		5 5	90	ns
Output Fall Time	C _L = 1 mF		55	90		55	90	ns
Undervoltage Lockout	Section							
Undervoltage Threshold		6.6	7	7.3	6.6	7	7.3	V
Start Threshold		7.5	7.8	8	7.5	7.8	8	V
Threshold Hysteresis		0.6	0.8	1	0.6	0.8	1	V
Total Standby Current								
Supply Current		_	1.2	2.5	—	1.2	2	mA
Start-Up Current		_	250	350		250	3 50	μА

- NOTES: 1. These parameters, although guaranteed over the recommended operating conditions, are not tested in production.
 - 2. Parameter measured at trip point of latch with V_{Pin 6} = VREF, VPin 16 = 0V.
 - 3. Amplifier gain is defined as:G = $\frac{\Delta V p_{in} 7}{\Delta V p_{in} 4}$; $\Delta V p_{in} 4 = 0V$ to 1V
- 4. Current into Pin 1 guaranteed to latch circuit in shutdown state.
- 5. Current into Pin 1 guaranteed not to latch circuit in shutdown state.

Peak Current Limit Setup

Resistors R1 and R2 at the current limit input (pin 1) set the peak current limit (Figure 1). The potential at pin 1 is easily calculated:

$$V1 = V_{REF} \frac{R2}{R1 + R2}$$

R1 should be selected first. The shutdown circuit feature is not latched for ($V_{REF} = 0.35$)/R1 <65 μ A and is latched for currents greater than 140 μ A.

The error amplifier output voltage is clamped from going above V1 through the limit buffer amplifier. Peak current is sensed by RS and amplified by the current amplifier which has a fixed gain of 3.

I_{PCL}, the peak current limit, is the current that causes the PWM comparator noninverting input to exceed V1; the potential at the inverting input. Once the comparator trip point is exceeded, both outputs are disabled.

IPCL is easily calculated:

$$I_{PCL} = \frac{V1 - 0.65V}{3 (RS)}$$

where:

$$V1 = V_{REF} \frac{R2}{R1 + R2}$$

V_{REF} = Internal voltage reference = 5.1V 3 = Gain of current-sense amplifier 0.65V = Current limit offset

Both driver outputs (pins 11 and 14) are OFF (low) when the peak current limit is exceeded. When the sensed current goes below I_{PCL}, the circuit operates normally.

Output Shutdown

The outputs can be turned off quickly through the shutdown input (pin 16). A signal greater than 360 mV at pin 16 forces the shutdown comparator output high. The PWM latch is held set, disabling the outputs.

Q2 is also turned on. If $V_{REF}/R1$ is greater than 140 μ A, positive feedback through the lock-up amplifier and Q1 keeps the inverting PWM comparator inverting input below 0.65V. Q3 remains on even after the shutdown input signal is removed. This is because the lock-up amplifier is in latched mode driving Q3 on. This state can be cleared only through a power-up cycle. Outputs will be disabled whenever the potential at pin 1 is below 0.65V.

The shutdown terminal gives a fast, direct way to disable the PWM controller output transistors. System protection and remote shutdown applications are possible.

The input pulse to pin 16 should be at least 100 ns wide and have an amplitude of at least 1V in order to get the minimum propagation delay from input to output. If these parameters are met, the delay should be less than 400 ns at 25°C; however, the delay time will increase as the device temperature rises.

Soft Restart From Shutdown

A soft restart can be programmed if nonlatched shutdown operation is used.

A capacitor at pin 1 will cause a gradual increase in potential toward V1. When the voltage at pin 1 reaches 0.75V, the PWM latch set input is removed and the circuit establishes a regulated output voltage. The soft-start operation forces the PWM output drivers to initially operate with minimum duty cycle and low peak currents.

Even if a soft start is not required, it is necessary to insert a capacitor between pin 1 and ground if the current I_L is greater than 140 µA. This capacitor will prevent "noise triggering" of the latch, yet minimize the soft-start effect.

Soft-Start Power-Up

During power-up, a capacitor at R1, R2 initiates a softstart cycle. As the input voltage (pin 15) exceeds the undervoltage lockout potential (7V), Q4 is turned off, ending undervoltage lockout. Whenever the PWM comparator inverting input is below 0.65V, both outputs are disabled.

When the undervoltage lockout start threshold is exceeded, the capacitor begins to charge. The PWM duty cycle increases until the operating output voltage is reached. Soft-start operation forces the PWM output drivers to initially operate with minimum duty cycle and low peak current.

Current-Sense Amplifier

The current-sense amplifier operates at a fixed gain of 3. Maximum differential input voltage ($V_{PIN4}-V_{PIN3}$) is 1.1V. Common-mode input voltage range is 0V to V_{IN} – 3V.

Resistive-sensing methods are shown in Figure 2. In Figure 2(A), a simple RC filter limits transient voltage spikes at pin 4, caused by external output transistor-collector capacitance. Transformer coupling (Figure 3) offers isolation and better power efficiency, but cost and complexity increase.

In order to minimize the propagation delay from the input to the current amplifier to the output terminals, the current ramp should be in the order of 1 μ s in width (min). Typical time delay values are in the 225 ns region at 25°C. The delay time increases with device temperature so that at 50°C, the delay times may be increased by as much as 100 ns.

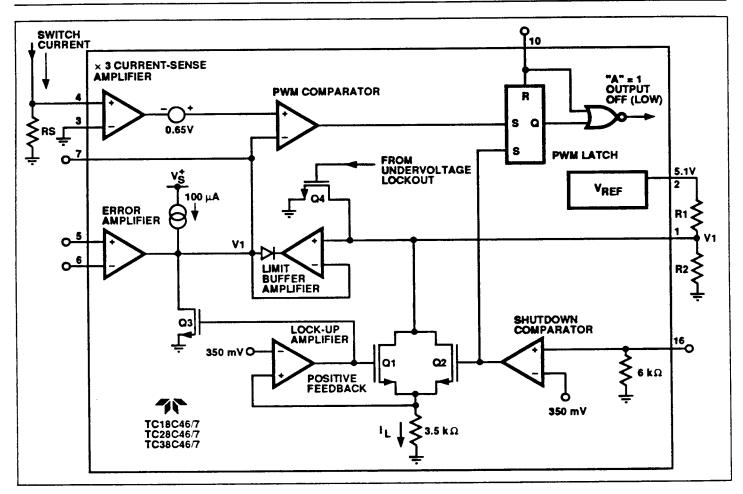


Figure 1 R1 and R2 Set Maximum Peak Output Current

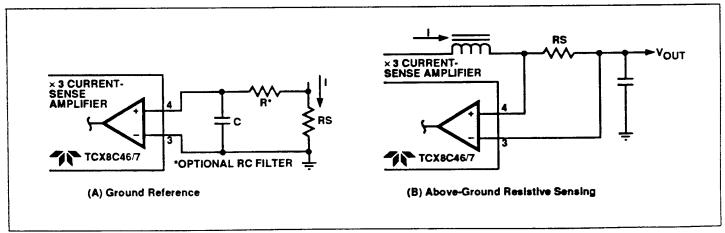


Figure 2 Resistive Sensing

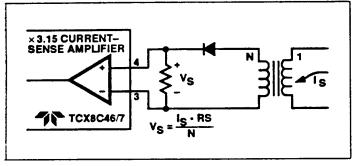


Figure 3 Transformer Isolated Current Sense

Under Voltage Lockout

The under voltage lockout circuit forces the PWM controller outputs OFF (low) if the supply voltage is below 7V. Threshold hysteresis is 0.8V and guarantees clean, jitterfree turn-on and turn-off points. The hysteresis also reduces capacitive filtering requirements at the PWM controller supply input (pin 15).

Circuit Synchronization

Current-mode-controlled power supplies can be operated in parallel with a common load. Paralleled converters will equally share the load current. Voltage-mode controllers unequally share the load current, decreasing system reliability.

Two or more of these PWM controllers can be slaved together for parallel operation. Circuits can operate from a master PWM controller internal oscillator with an external driver (Figure 4). Devices can also be slaved to an external oscillator (Figure 5). Disable internal slave device oscillators by grounding pin 8. Slave controllers derive an oscillator from the bidirectional synchronization output signal at pin 10.

Pin 10 is bidirectional in that it is intended to be both a sync output and input. This is accomplished by making the output driver "weak." This is advantageous in that it eliminates an additional pin from the package but does not enable the device to directly drive another device. In order to make it an effective driver, a buffer is required (Figure 4). In order to use pin 10 as a sync input, it is necessary to overcome the internal driver. This requires a pulse with an amplitude equal to V_S. Since V_S must be above 7V for the undervoltage lockout to be disabled, a CMOS or opencollector TTL driver should be used.

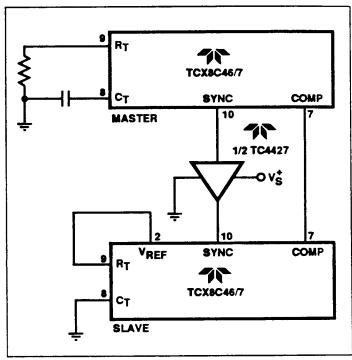


Figure 4 Master/Slave Parallel Operation

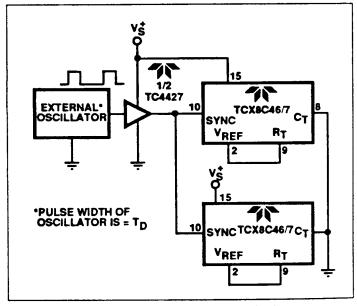


Figure 5 External Clock Synchronization

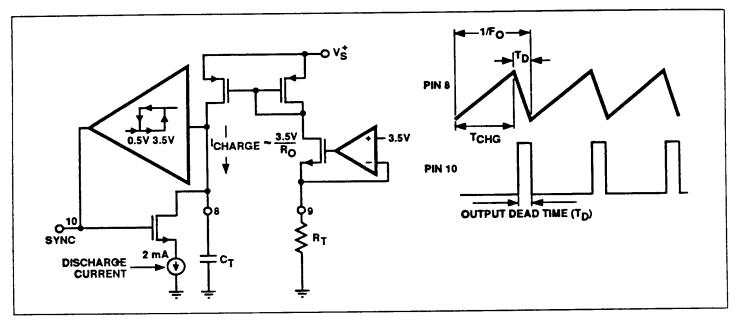


Figure 6 Oscillator Circuit

Selection of Timing Capacitor and Resistor $(C_T \& R_T)$

First determine the frequency of operation desired for Fo. Select amount of dead time desired for T_D.

Calculate timing capacitor CT

$$C_T = \frac{I_{DIS} \times T_D}{3}$$

Calculate capacitor charge time, T_{CHG} TCHG = 1/Fo - TD

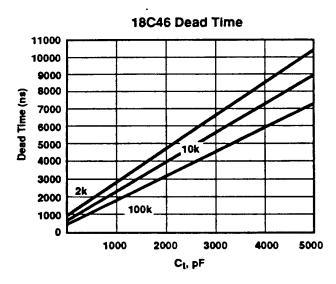
Calculate the capacitor charging current, ICHARGE

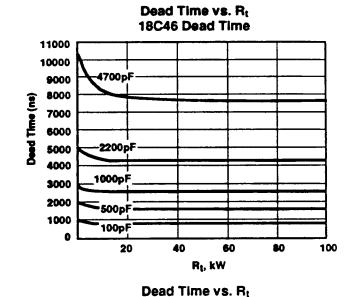
$$I_{CHARGE} = \frac{3C_{T}}{T_{CHG}}$$

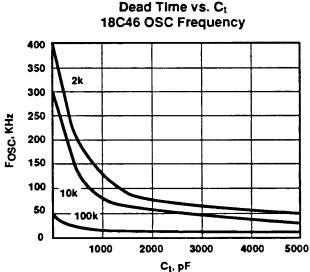
Calculate timing resistor RT

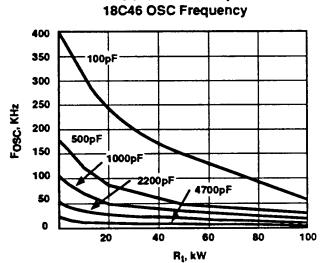
$$R_T = \frac{3.5}{I_{CHARGE}}$$

TYPICAL CHARACTERISTIC CURVES





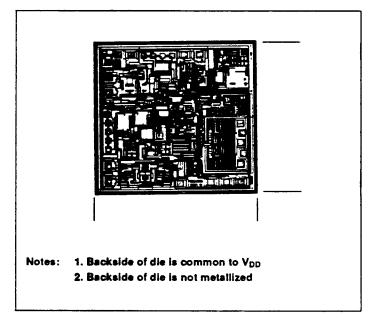




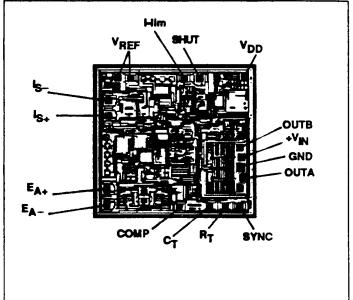
PIN DESCRIPTIONS

PIN	DESCRIPTION
1	CURRENT LIMIT, SOFT START ADJUST pin is for setting the peak current limit threshold of sense inputs of pin 3 and 4. Second function of this pin is for Soft-Start programming with a capacitor between this pin and ground, pin 12.
2	V _{REF} pin is an output for the reference supply voltage of 5.1 volts. This reference can supply a minimum of 20 mA of output current.
3	 CURRENT SENSE INPUT pin is for current sense inverting input for sensing peak current of pass transistor through series current monitor resistor.
4	+ CURRENT SENSE INPUT pin is the non-inverting input for sensing peak current of pass transistor. The positive end of the current sense resistor is connected here.
5	+ ERROR AMP INPUT pin is the non-inverting input for sensing voltage feedback from output or voltage regulation.
6	- ERROR AMP INPUT pin is the inverting input for sensing the reference voltage to regulate the output.
7	COMPENSATION pin is for compensation of the feedback loop response.
8	C_T pin is for timing capacitor, C_T input to set oscillator frequency in conjunction with pin 9, R_T , resistor input. Second function is for setting crossover dead time of pin 11 and 14 outputs.
9	R_T pin if for timing resistor, R_T input to set oscillator frequency by setting the constant current charge rate to charge capacitor, C_T .
10	SYNC pin is for input or output of oscillator synchronization pulse.
11	OUTPUT A pin is the output drive of phase A to drive push pull transistor of phase A.
12	GROUND pin is the ground return path for all inputs and output signals.
13	V _{DD} pin is the supply power input terminal which supplies power to operate the output drivers.
14	OUTPUT B pin is the output drive of phase B to drive push pull transistor of phase B.
15	V _{IN} pin is voltage bias supply input for circuits except the output drive circuits.
16	SHUTDOWN pin is an input for shutdown when 350 mV threshold is exceeded. Both output drives will be terminated.

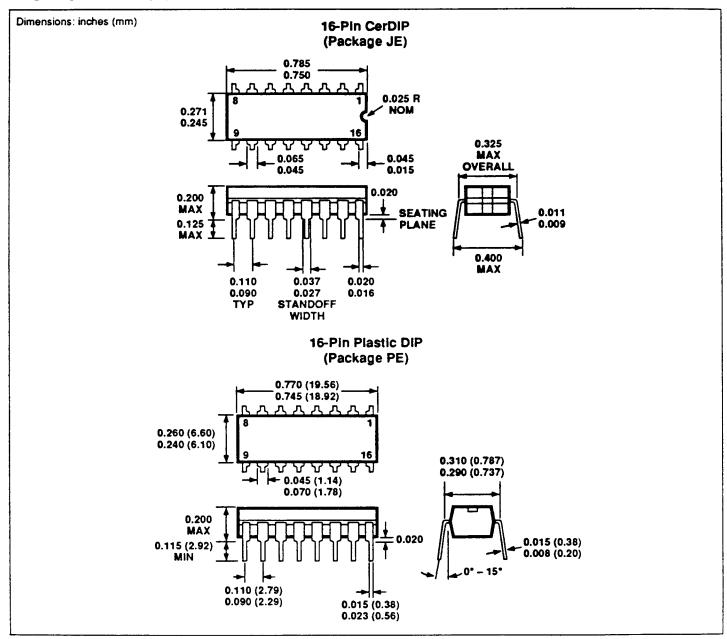
BONDING DIAGRAM



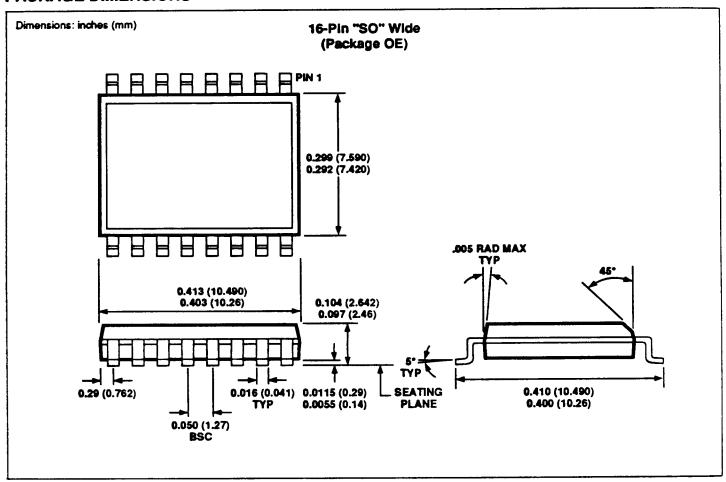
OUTPUT LOCATIONS



PACKAGE DIMENSIONS



PACKAGE DIMENSIONS



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